PNZ147 (PN147)

Silicon planar type

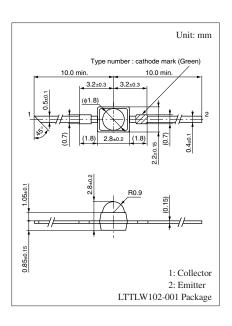
For optical control systems

■ Features

- High sensitivity
- Wide spectral sensitivity characteristics, suited for detecting GaAs LEDs
- Fast response: t_r , $t_f = 3 \mu s$ (typ.)
- Small size designed for easier mounting to printed circuit board

■ Absolute Maximum Ratings $T_a = 25$ °C

| Parameter | Symbol | Rating | Unit |
|---------------------------------------|------------------|-------------|------|
| Collector-emitter voltage (Base open) | V _{CEO} | 20 | V |
| Emitter-collector voltage (Base open) | V _{ECO} | 5 | V |
| Collector current | I_C | 20 | mA |
| Collector power dissipation | P _C | 50 | mW |
| Operating ambient temperature | T _{opr} | -25 to +85 | °C |
| Storage temperature | T_{stg} | -30 to +100 | °C |



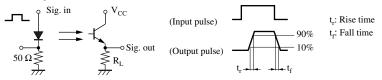
■ Electrical-Optical Characteristics $T_a = 25$ °C ± 3 °C

| Parameter | Symbol | Conditions | Min | Тур | Max | Unit |
|---|------------------------|---|-----|------|------|------|
| Photocurrent *1 | I _{CE(L)1} *2 | $V_{CE} = 10 \text{ V}, L = 2 \text{ lx}$ | 3 | 12 | | μΑ |
| | I _{CE(L)2} | $V_{CE} = 10 \text{ V}, L = 500 \text{ lx}$ | | 3.5 | | mA |
| Dark current | I_{CEO} | $V_{CE} = 10 \text{ V}$ | | 0.01 | 0.50 | μΑ |
| Peak emission wavelength | λ_{p} | $V_{CE} = 10 \text{ V}$ | | 800 | | nm |
| Half-power angle | θ | The angle from which photocurrent becomes 50% | | 24 | | 0 |
| Rise time *3 | t _r | $V_{CC} = 10 \text{ V}, I_{CE(L)} = 5 \text{ mA}, R_L = 100 \Omega$ | | 3 | 10 | μs |
| Fall time *3 | t _f | | | 3 | 10 | μs |
| Collector-emitter saturation voltage *1 | V _{CE(sat)} | $I_{CE(L)} = 1 \text{ mA}, L = 1000 \text{ lx}$ | | 0.2 | 0.5 | V |

- Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.
 - 2. Spectral sensitivity characteristics: Sensitivity for wave length over 400 nm maximum sensitivity ratio is 100%.
 - 3. This device is designed be disregarded radiation.
 - 5. *1: Source: Tungsten (color temperature 2856 K)
 - *2: Rank classification

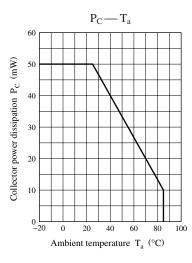
| Rank | Q | R | S |
|-------------------------------|-------------|-------------|-------|
| $I_{CE(L)}\left(\mu A\right)$ | 3.0 to 11.0 | 7.0 to 24.0 | >16.0 |

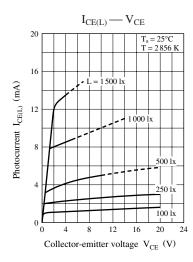
*3: Switching time measurement circuit

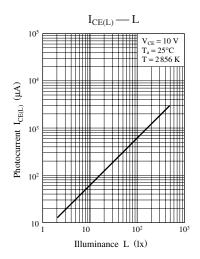


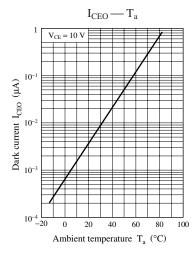
Note) The part number in the parenthesis shows conventional part number.

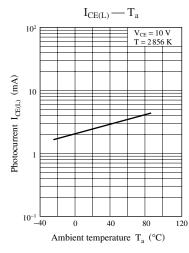
PNZ147 Panasonic

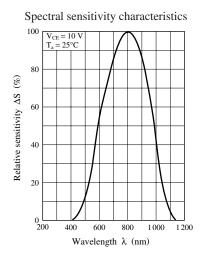




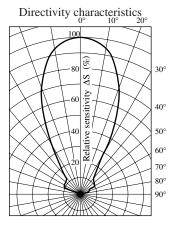


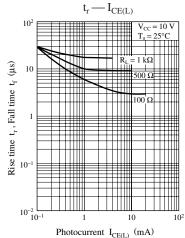






 $t_f - I_{CE(L)}$





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